

ACMS64P06H8-HF

P-Channel
RoHS Device
Halogen Free

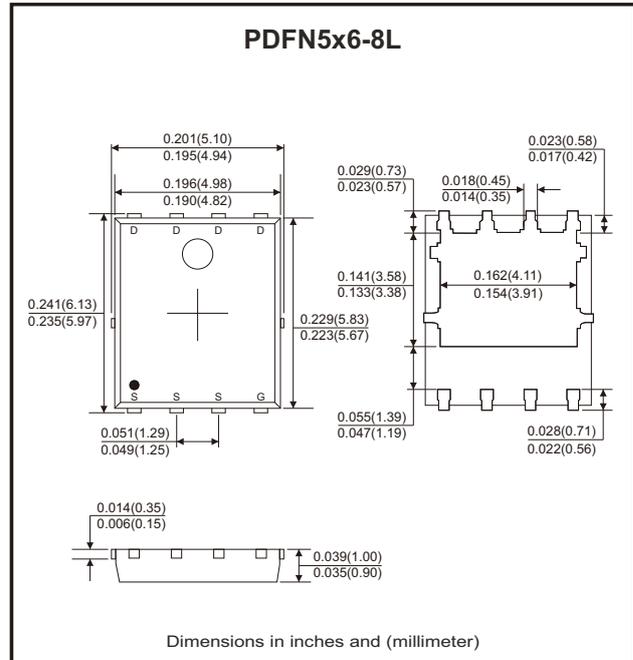


Features

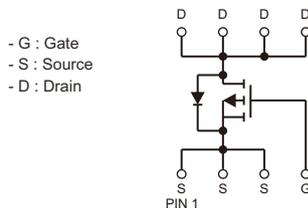
- High density cell design for ultralow RDS(ON).
- Fully characterized avalanche voltage and current.
- Good stability and uniformity with high EAS.
- Excellent package for good heat dissipation.
- AEC-Q101 Qualified.

Mechanical data

- Case: PDFN5x6-8L, molded plastic.
- Molding compound: UL flammability classification rating 94V-0.
- Terminals: Matte tin plated leads, solderable per MIL-STD-202, method 208.



Circuit Diagram



Maximum Ratings (at Tc=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V _{DS}	-60	V
Gate-source voltage	V _{GS}	±20	V
Continuous drain current (T _c =25°C)	I _D	-64	A
Continuous drain current (T _c =100°C)	I _D	-45	
Pulsed drain current (t _p = 10μs, T _c =25°C)	I _{DM}	-256	A
Avalanche energy, single pulse (Note 4)	E _{AS}	120	mJ
Power dissipation (T _c =25°C)	P _D	136	W
Thermal resistance junction to air (Note 1)	R _{θJA}	40	°C/W
Thermal resistance junction to case	R _{θJC}	1.1	°C/W
Operating junction temperature range	T _J	-55 to +175	°C
Storage temperature range	T _{STG}	-55 to +175	°C

Electrical Characteristics (at T_c=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{DSS}	V _{GS} = 0V, I _D = -250μA	-60			V
Zero gate voltage drain current	I _{DSS}	V _{DS} = -60V, V _{GS} = 0V			-1	μA
Gate-body leakage current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V			±100	nA
On Characteristics (Note 2)						
Static drain-source on-resistance	R _{DS(on)}	V _{GS} = -10V, I _D = -20A			16	mΩ
	R _{DS(on)}	V _{GS} = -4.5V, I _D = -20A			19	mΩ
Gate threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250μA	-1	-1.7	-2.5	V
Gate resistance	R _G	V _{GS} = 0V, f = 1 MHz		3.2		Ω
Dynamic Characteristics						
Forward transconductance	g _{fs}	V _{DS} = -5V, I _D = -20A		25		S
Input capacitance	C _{iss}	V _{GS} = 0V, V _{DS} = -30V, f = 1MHz		5007		pF
Output capacitance	C _{oss}			337		
Reverse transfer capacitance	C _{rss}			246		
Switching Characteristics						
Turn-on delay time (Note 3)	t _{d(on)}	V _{DD} = -30V, V _{GS} = -10V, R _G = 3Ω, R _L = 1.5Ω		18		ns
Turn-on rise time (Note 3)	t _r			20		
Turn-off delay time (Note 3)	t _{d(off)}			55		
Turn-off fall time (Note 3)	t _f			35		
Total gate charge	Q _g	V _{DD} = -30V, V _{GS} = -10V, I _D = -20A		93		nC
Gate to source charge	Q _{gs}			15.7		
Gate to drain (miller) charge	Q _{gd}			15.8		
Source-Drain Diode Characteristics						
Diode forward voltage (Note 2)	V _{SD}	I _{SD} = -20A, V _{GS} = 0V, T _J = 25°C		-0.8	-1.2	V
Reverse recovery time	t _{rr}	I _F = -20A, V _{GS} = 0V, dI _F /dt = 100A/μs		40		ns
Reverse recovery charge	Q _{rr}				35	

- Notes: 1. Surface mounted on 1 inch² FR-4 board with 2OZ copper.
 2. The data tested by pulsed, pulse width ≤ 300μs, duty cycle ≤ 2%.
 3. Guaranteed by design, not subject to production.
 4. EAS condition: T_J=25°C, V_{DD}=-30V, V_{GS}=-10V, L=0.5mH, R_G=25Ω.

Typical Rating and Characteristic Curves (ACMS64P06H8-HF)

Fig.1 - Typical Output Characteristics

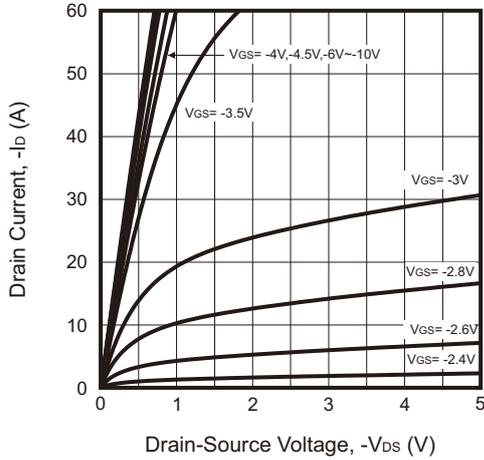


Fig.2 - On-Resistance vs. Drain Current and Gate Voltage

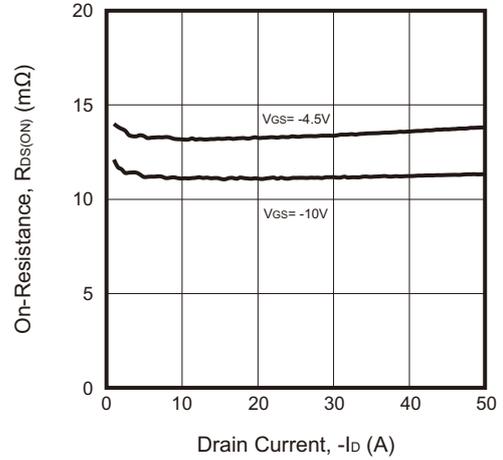


Fig.3 - On-Resistance vs. Gate-Source Voltage

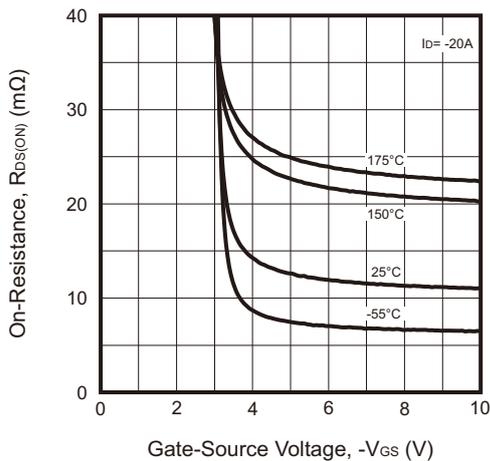


Fig.4 - Body-Diode Characteristics

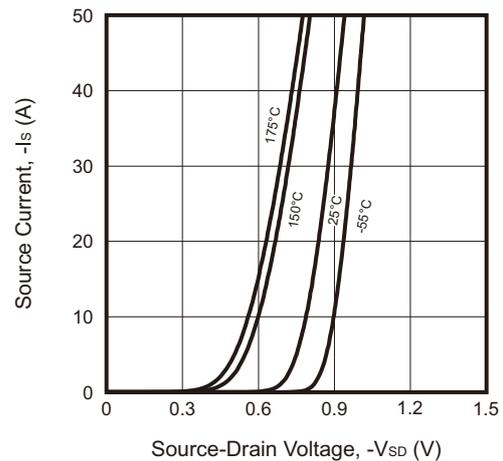


Fig.5 - Normalized On-Resistance vs. Junction Temperature

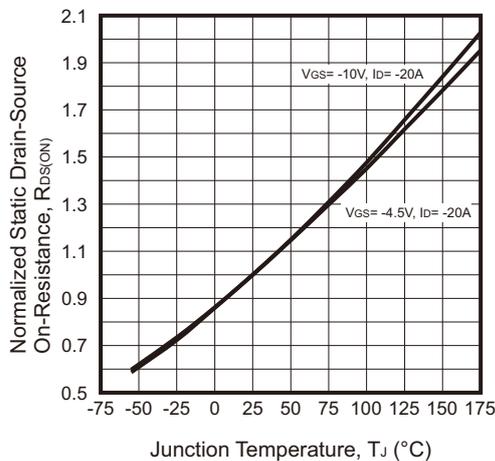
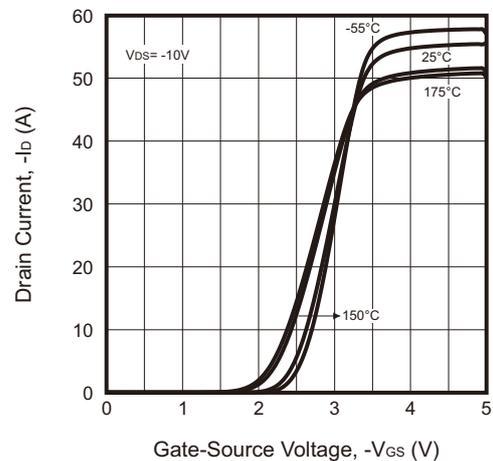


Fig.6 - Transfer Characteristics



Typical Rating and Characteristic Curves (ACMS64P06H8-HF)

Fig.7 - Capacitance Characteristics

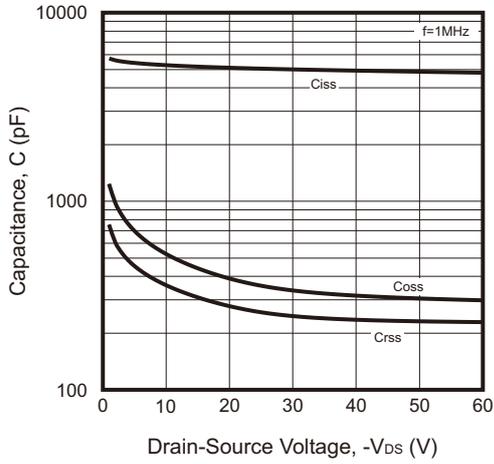


Fig.8 - Gate Charge Characteristics

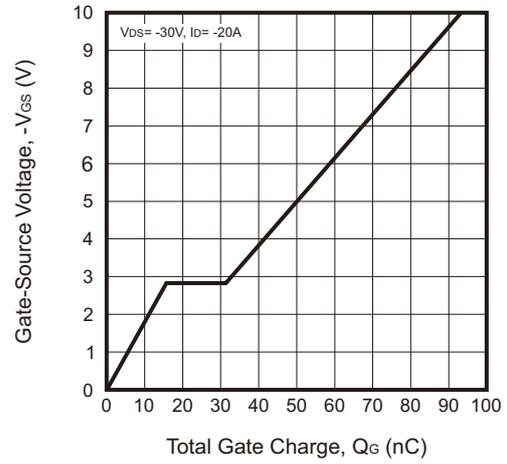


Fig.9 - Normalized Breakdown Voltage vs. Junction Temperature

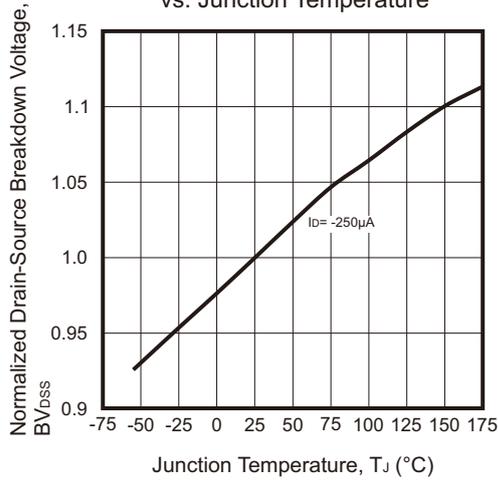
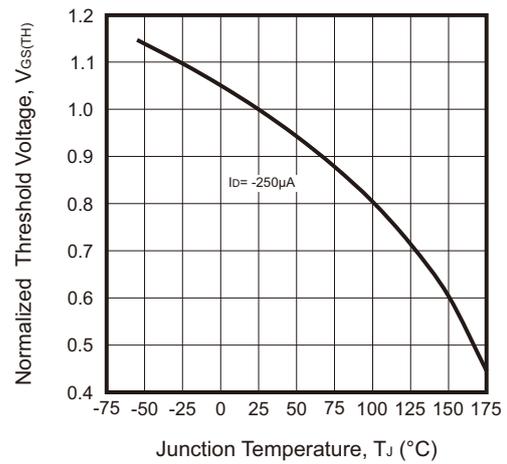
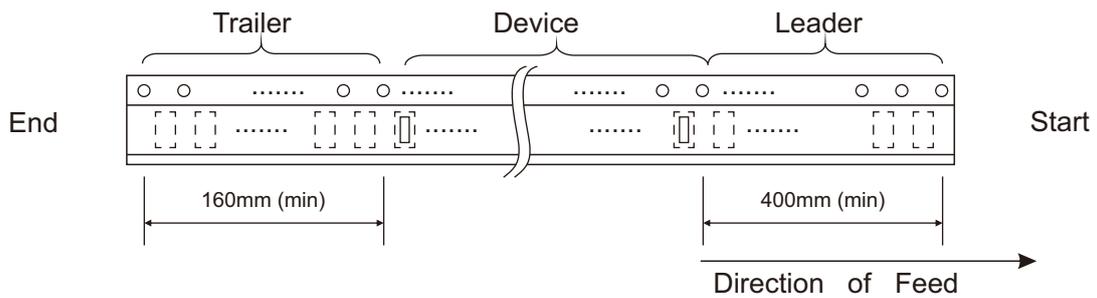
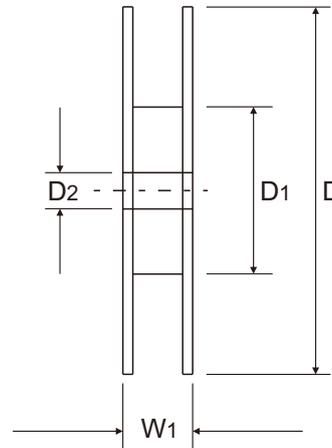
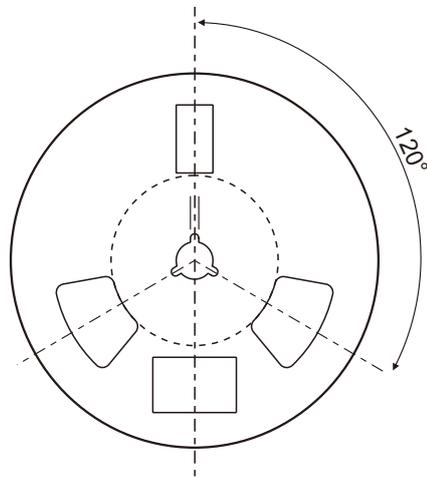
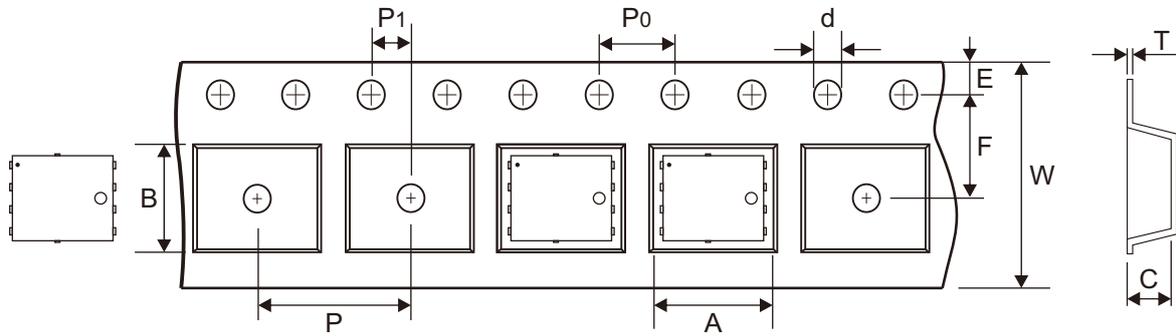


Fig.10 - Normalized V_{GS(th)} vs. Junction Temperature



Reel Taping Specification

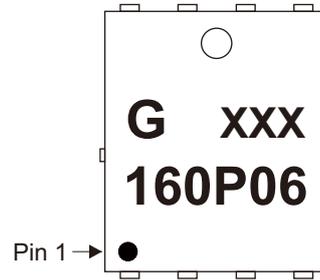


PDFN5x6-8L	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	6.30 ± 0.10	5.30 ± 0.10	1.20 ± 0.10	1.55 + 0.01	330 ± 2.00	100 ± 2.00	13.00 ± 0.20
	(inch)	0.248 ± 0.004	0.209 ± 0.004	0.047 ± 0.004	0.061 + 0.0004	12.992 ± 0.079	3.937 ± 0.079	0.512 ± 0.008

PDFN5x6-8L	SYMBOL	E	F	P	P0	P1	T	W	W1
	(mm)	1.75 ± 0.10	5.50 ± 0.10	8.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	0.25 ± 0.03	12.00 + 0.30 - 0.10	18.50 ± 2.00
	(inch)	0.069 ± 0.004	0.217 ± 0.004	0.315 ± 0.004	0.157 ± 0.004	0.079 ± 0.002	0.010 ± 0.001	0.472 + 0.012 - 0.004	0.728 ± 0.079

Marking Code

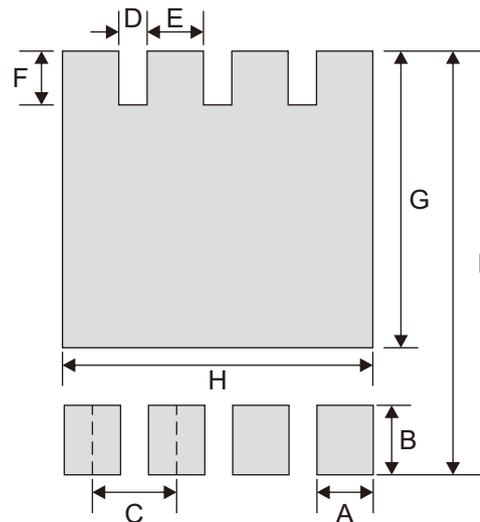
Part Number	Marking Code
ACMS64P06H8-HF	160P06



XXX = Control code

Suggested P.C.B. PAD Layout

SIZE	PDFN5x6-8L	
	(mm)	(inch)
A	0.80	0.031
B	1.00	0.039
C	1.27	0.050
D	0.47	0.019
E	0.80	0.031
F	0.85	0.033
G	4.50	0.177
H	4.61	0.181
I	6.40	0.252



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
PDFN5x6-8L	5,000	13